Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-113-6770

Ir	nclosure Material:
С	Ceramic and metal
С	Overall Length:
1	.430 inches
F	unction For Which Designed:
R	Rectifier
N	Nounting Facility Quantity:
1	
J	oint Electronic Device Engineering Council/jedec/case Outline Designation
D	Do-5
N	Nounting Method:
Т	Threaded stud
С	Overall Width Across Flats:
0	.690 inches
т	hread Size:
0	.250 inches
S	Semiconductor Material:
S	Silicon
v	oltage Rating In Volts Per Characteristic:
5	0.0 reverse voltage, peak
С	Current Rating Per Characteristic:
5	00.00 microamperes forward current, average peak
N	Iaximum Operating Tempurature Per Measurement Point:
1	50.0 degrees celsius ambient air
Т	hread Series Designator:
U	Jnf
Т	erminal Type And Quantity:
1	tab, solder lug and 1 threaded stud
S	Shelf Life:
Ν	I/a
U	Init Of Measure:
D	Demilitarization:
Ν	lo
F	iig:
A	110a0